BCR10CM-16LH

800V - 10A - Triac

Medium Power Use

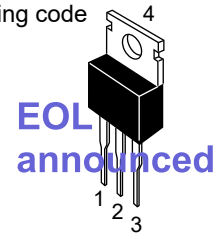
R07DS0320EJ0300
Rev.3.00
Feb. 1, 2019

Features

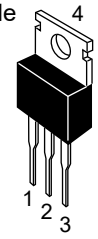
- $I_{T\,(RMS)}$: 10 A
- V_{DRM} : 800 V
- I_{FGTI}, I_{RGTI}, $I_{RGT\,III}$: 50 mA or 35 mA(I_{GT} item:1)
- Tj: 150°C
- Planar Passivation Type
- High Commutation

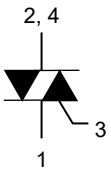
Outline

RENESAS Package code: PRSS0004AG-A
(Package name: TO-220AB)
Ordering code
#BB0



RENESAS Package code: PRSS0004AT-A
(Package name: TO-220ABA)
Ordering code
#BH0





1. T_1 Terminal
2. T_2 Terminal
3. Gate Terminal
4. T_2 Terminal

Application

Power supply, motor control, heater control, solenoid control, and other general purpose AC control applications.

Maximum Ratings

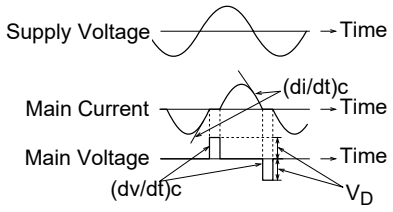
Parameter	Symbol	Voltage class	Unit
		16	
Repetitive peak off-state voltage[Note1]	V_{DRM}	800	V
Non-repetitive peak off-state voltage[Note1]	V_{DSM}	960	V

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	$I_{T\,(RMS)}$	10	A	Commercial frequency, sine full wave 360°conduction, Tc = 128°C[Note3]
Surge on-state current	I_{TSM}	100	A	60 Hz sinewave 1 full cycle, peak value, non-repetitive
I^2t for fusion	I^2t	41.6	A^2s	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	P_{GM}	5	W	
Average gate power dissipation	$P_{G\,(AV)}$	0.5	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I_{GM}	2	A	
Junction Temperature	Tj	–40 to +150	°C	
Storage temperature	Tstg	–40 to +150	°C	

Electrical Characteristics

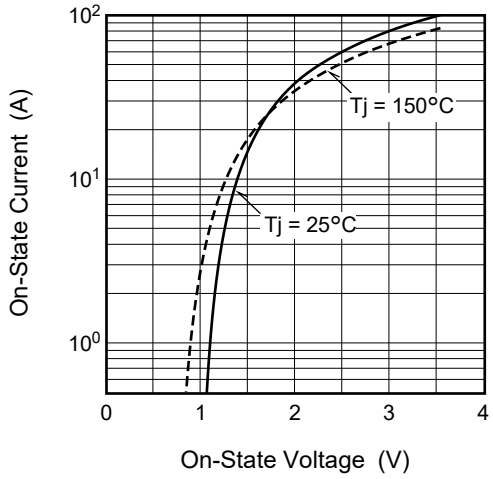
Parameter		Symbol	BCR10CM-16LH-1 (I_{GT} item:1)			BCR10CM-16LH			Unit	Test conditions
			Min.	Typ.	Max.	Min.	Typ.	Max.		
Repetitive peak off-state current		I_{DRM}	—	—	2.0	—	—	2.0	mA	Tj = 150°C V_{DRM} applied
On-state voltage		V_{TM}	—	—	1.5	—	—	1.5	V	Tc = 25°C, I_{TM} = 15 A instantaneous measurement
Gate trigger voltage[Note2]	I	V_{FGTI}	—	—	1.5	—	—	1.5	V	Tj = 25°C, V_D = 6 V R_L = 6 Ω, R_G = 330 Ω
	II	V_{RGTI}	—	—	1.5	—	—	1.5	V	
	III	V_{RGTIII}	—	—	1.5	—	—	1.5	V	
Gate trigger current[Note2]	I	I_{FGTI}	—	—	35	—	—	50	mA	Tj = 25°C, V_D = 6 V R_L = 6 Ω, R_G = 330 Ω
	II	I_{RGTI}	—	—	35	—	—	50	mA	
	III	I_{RGTIII}	—	—	35	—	—	50	mA	
Gate non-trigger voltage		V_{GD}	0.2	—	—	0.2	—	—	V	Tj = 125°C V_D = 1/2 V_{DRM}
			0.1	—	—	0.1	—	—	V	Tj = 150°C V_D = 1/2 V_{DRM}
Thermal resistance		$R_{th\ (j-c)}$	—	—	1.8	—	—	1.8	°C/W	Junction to case[Note3,4]
Critical-rate of fall of on-state commutating current[Note5]		(di/dt)c	6	—	—	10	—	—	A/ms	Tj = 125°C (dv/dt)c < 100 V/μs

Notes: 1. Gate open.
2. Measurement using the gate trigger characteristics measurement circuit.
3. Case temperature is measured at the T_2 tab 1.5 mm away from the molded case.
4. The contact thermal resistance $R_{th(c-f)}$ in case of greasing is 1.0°C /W.
5. Test conditions of the critical-rate of fall of on-state commutation current are shown in the table below.

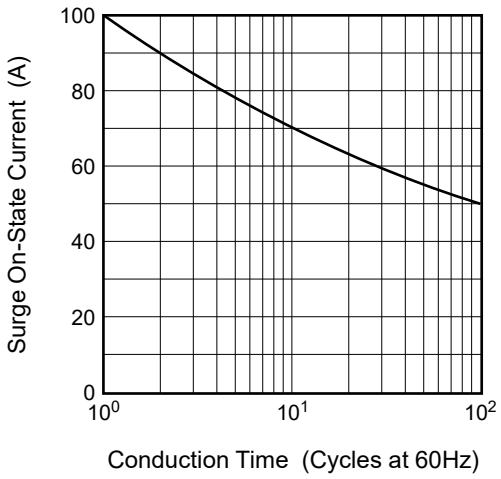
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature Tj = 125°C 2. Peak off-state voltage V_D = 400 V 3. Rate of rise of off-state commutating voltage (dv/dt)c < 100 V/μs	

Performance Curves

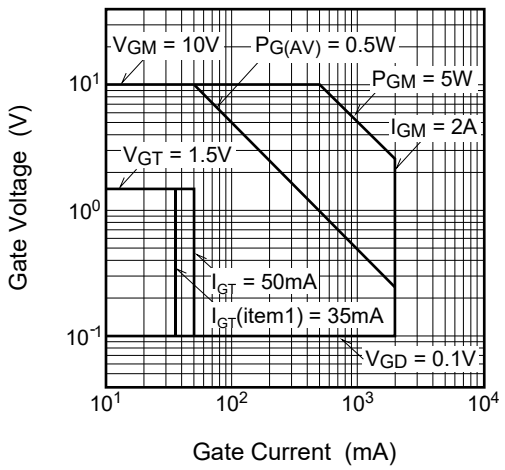
Maximum On-State Characteristics



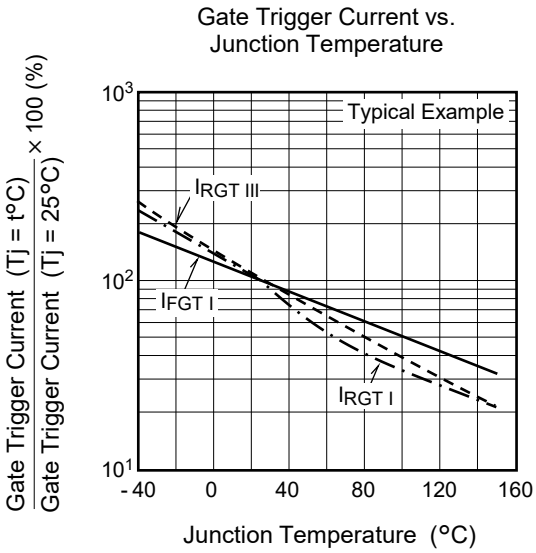
Rated Surge On-State Current



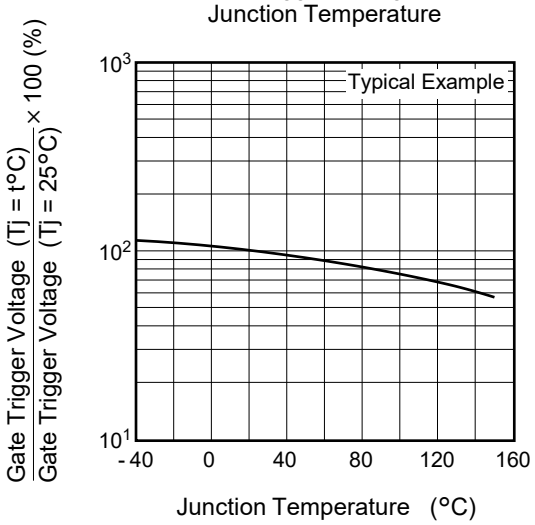
Gate Characteristics (I, II and III)



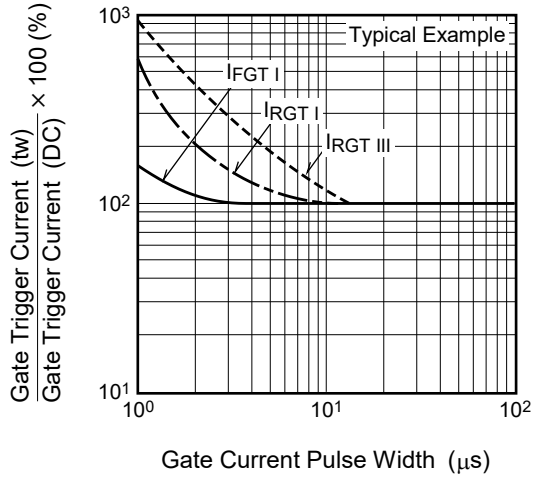
Gate Trigger Current vs. Junction Temperature



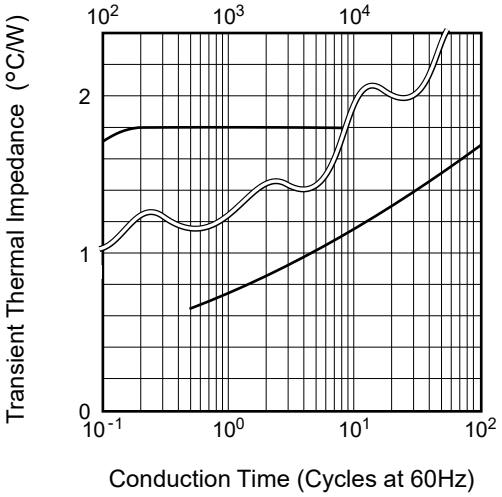
Gate Trigger Voltage vs. Junction Temperature



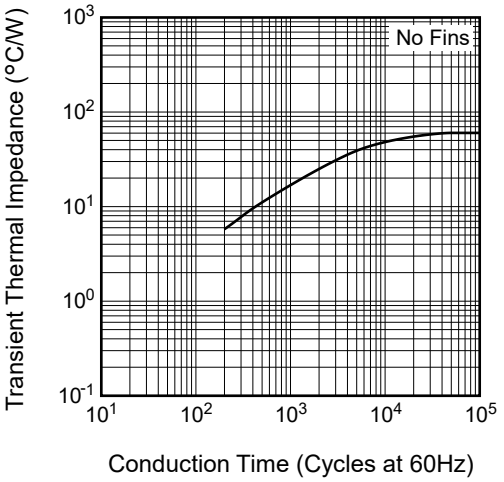
Gate Trigger Current vs. Gate Current Pulse Width



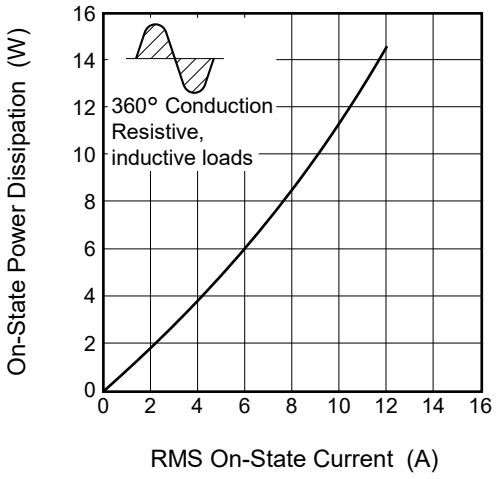
Maximum Transient Thermal Impedance Characteristics (Junction to case)



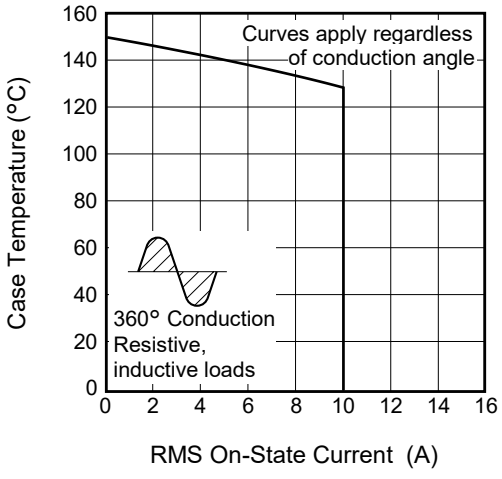
Maximum Transient Thermal Impedance Characteristics (Junction to ambient)



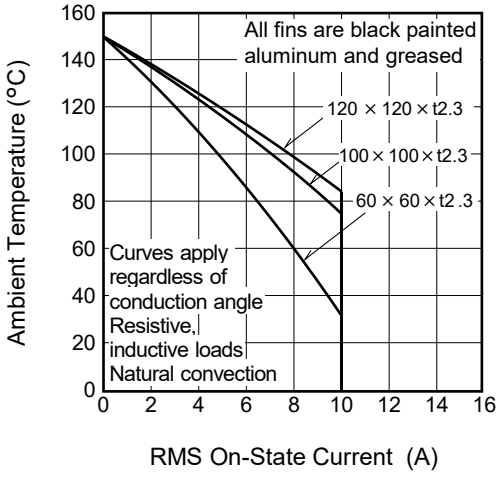
Maximum On-State Power Dissipation



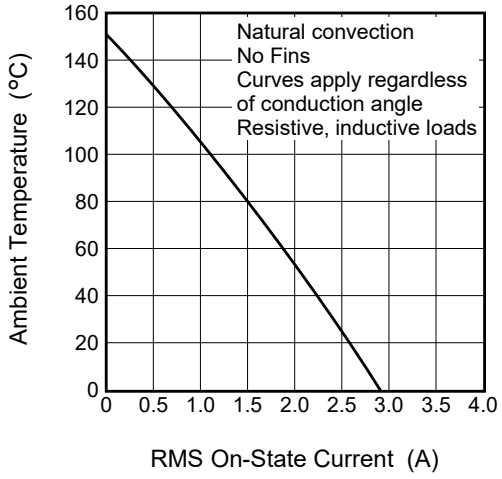
Allowable Case Temperature vs. RMS On-State Current



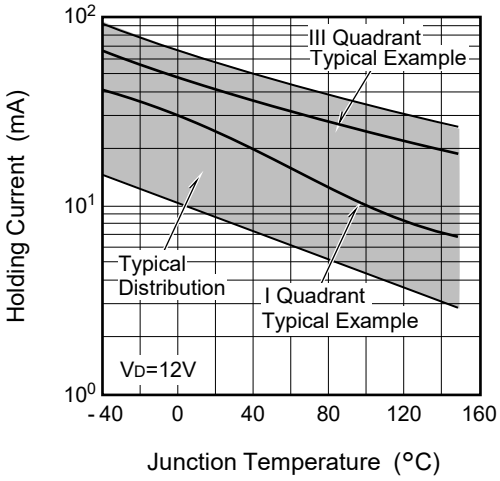
Allowable Ambient Temperature vs. RMS On-State Current



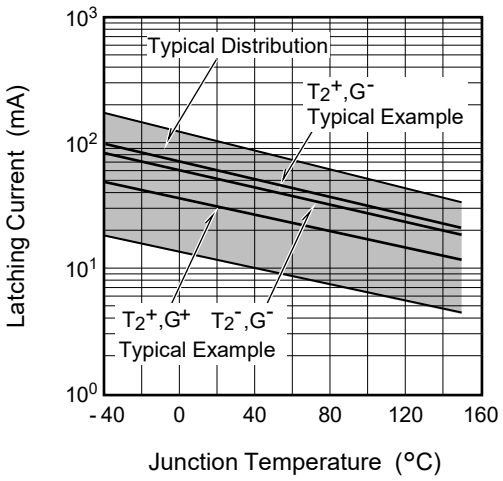
Allowable Ambient Temperature vs. RMS On-State Current



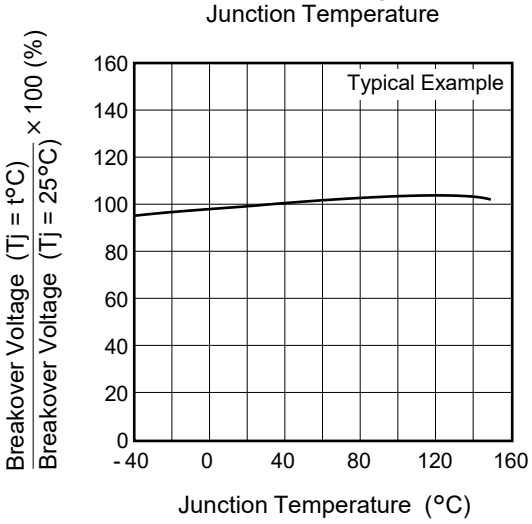
Holding Current vs.
Junction Temperature



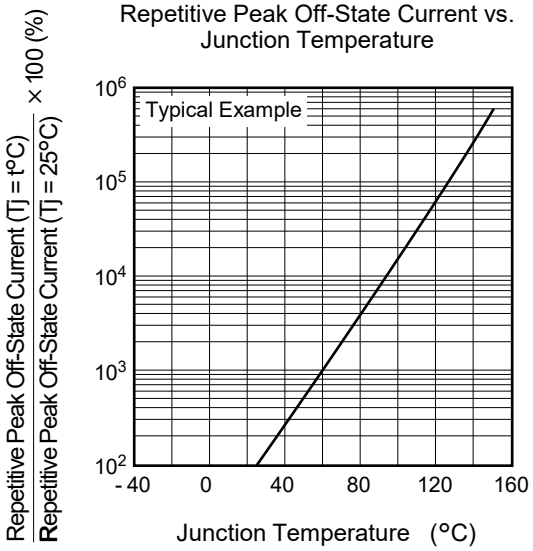
Latching Current vs.
Junction Temperature



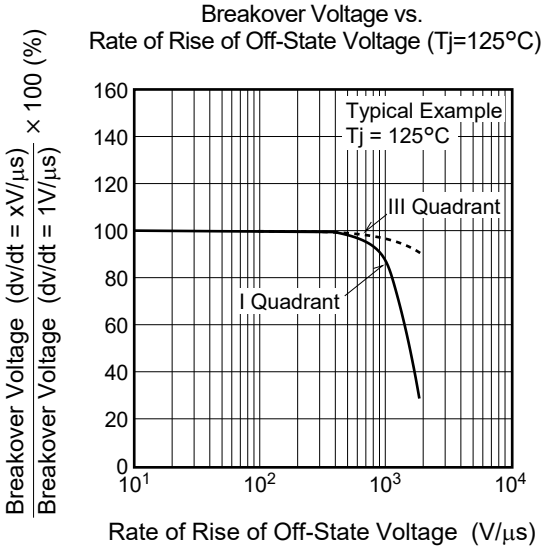
Breakover Voltage vs.
Junction Temperature



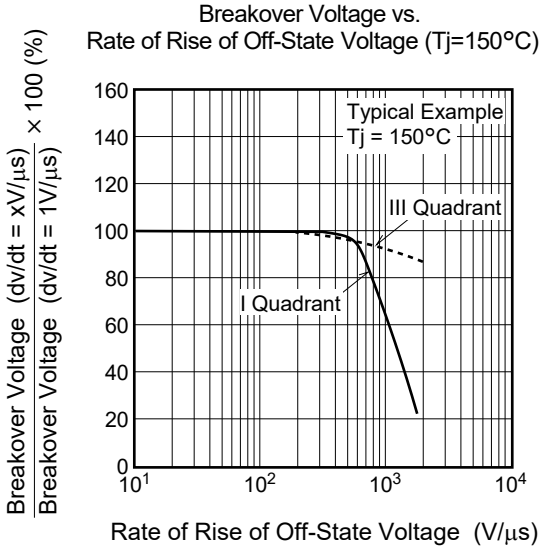
Repetitive Peak Off-State Current vs.
Junction Temperature



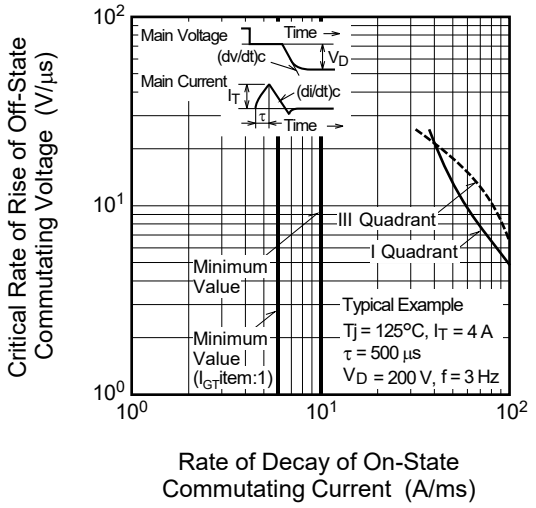
Breakover Voltage vs.
Rate of Rise of Off-State Voltage (Tj=125°C)



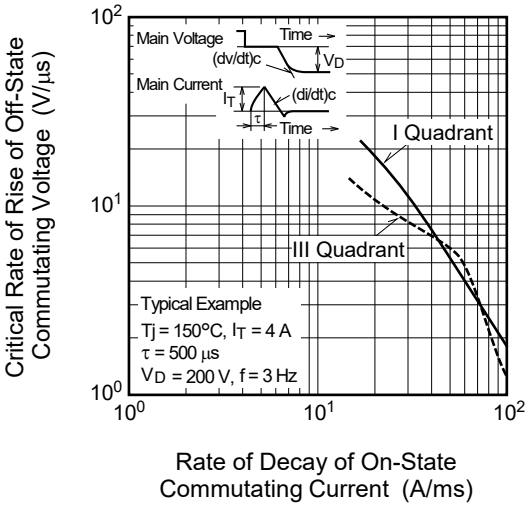
Breakover Voltage vs.
Rate of Rise of Off-State Voltage (Tj=150°C)



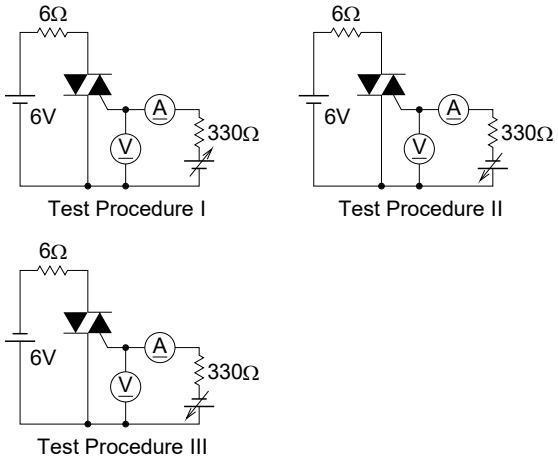
Commutation Characteristics (Tj=125°C)



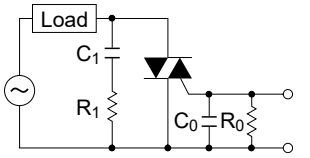
Commutation Characteristics (Tj=150°C)



Gate Trigger Characteristics Test Circuits



Recommended peripheral components for Triac



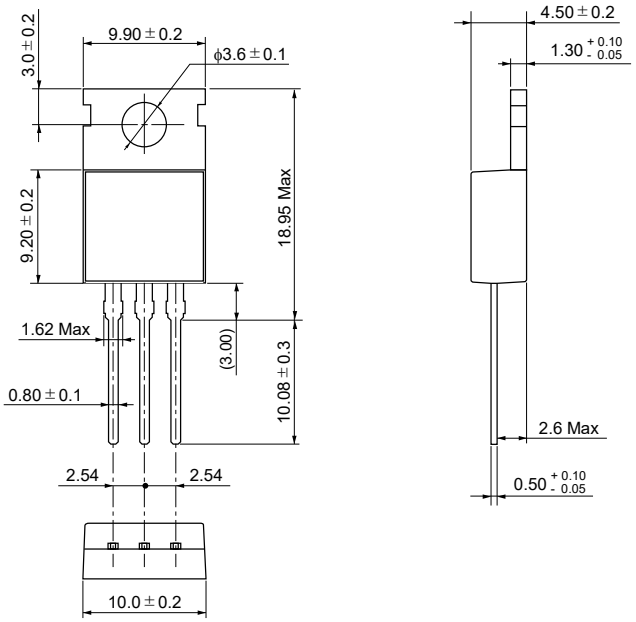
C_1 = 0.1 to 0.47 µF C_0 = 0.1 µF
R_1 = 47 to 100Ω R_0 = 100Ω

Package Dimensions

Ordering code: #BH0

Package Name	JEDEC Package Code	RENESAS Code	Previous Code	MASS[Typ.]
TO-220ABA	TO-220AB	PRSS0004AT-A	TO-220ABA	2.1g

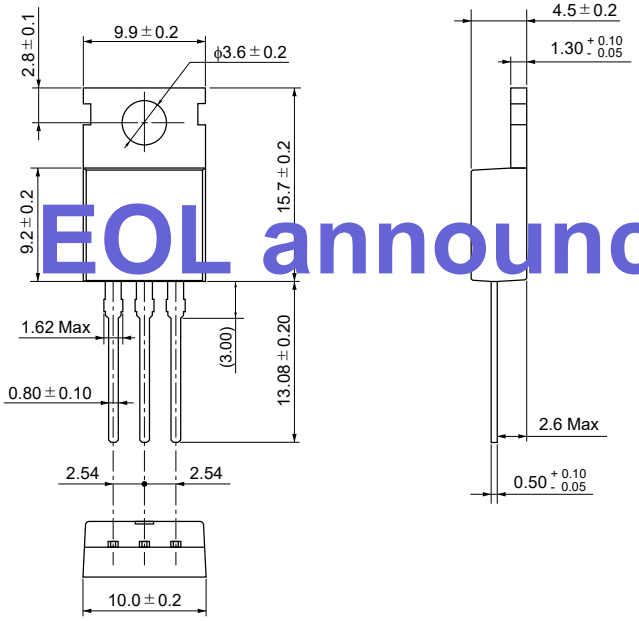
Unit: mm



Ordering code: #BB0

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
TO-220AB	SC-46	PRSS0004AG-A	TO-220ABS	2.1g

Unit: mm



Ordering Information

Orderable Part Number	Package	Quantity Note6	Remark	Status
BCR10CM-16LH#BH0	TO-220ABA	50 pcs./ tube	Straight type	Mass Production
BCR10CM-16LH-1#BH0	TO-220ABA	50 pcs./ tube	Straight type, I_{GT} item:1	
BCR10CM-16LH#BB0	TO-220ABS	50 pcs./ tube	Straight type	EOL announced
BCR10CM-16LH-1#BB0	TO-220ABS	50 pcs./ tube	Straight type, I_{GT} item:1	

Notes: 6. Please confirm the specification about the shipping in detail.

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